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**Date of birth:** 30 March 1992

**Education:**

- (1) 2009 – 2013 **BSc**  
Moscow Institute of Physics and Technology  
Department of General and Applied Physics  
Specialization: Applied Math and Physics  
Thesis: Fabrication of contacts on samples of superconducting monocrystals
- (2) 2013 – 2015 **MSc**  
Moscow Institute of Physics and Technology  
Department of General and Applied Physics  
Specialization: Applied Math and Physics  
Thesis: Cocrystals of drugs
- (3) 2015 – Present **PhD**  
Moscow Institute of Physics and Technology  
Department of Problems of Energetics and Physics  
Thesis: Cocrystals of drugs

**Work Experience:**

- (1) July 2013 – Present  
Junior Research Fellow, Computational Materials Discovery Laboratory, Moscow Institute of Physics and Technology
- (2) October 2014 – January 2015  
Engineer, Research and Development Department, Samsung
- (3) April 2014 – March 2015  
Scientific consultant, MIGO-group
- (4) October 2012 – June 2013  
Research trainee, Laboratory of strongly correlated electrons systems, Lebedev Institute of Physics, RAS